## BC337, BC337-25, BC337-40

# Amplifier Transistors NPN Silicon

### Features

• These are Pb-Free Devices

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CEO</sub>	45	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	50	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	800	mAdc
Total Device Dissipation @ $T_A = 25^{\circ}C$ Derate above 25°C	PD	625 5.0	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

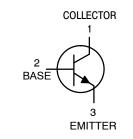
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

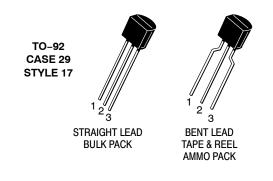
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



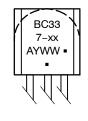
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### MARKING DIAGRAM



BC337-xx = Device Code (Refer to page 4) A = Assembly Location Y = Year WW = Work Week • = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

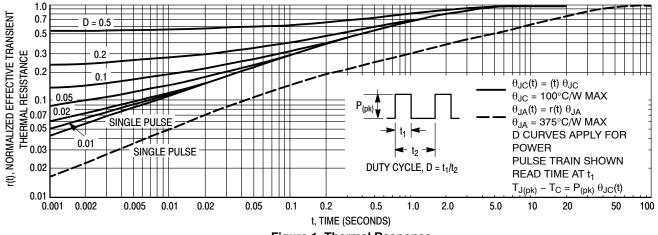
### BC337, BC337-25, BC337-40

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

(I<sub>C</sub> = 10 mA, V<sub>CE</sub> = 5.0 V, f = 100 MHz)

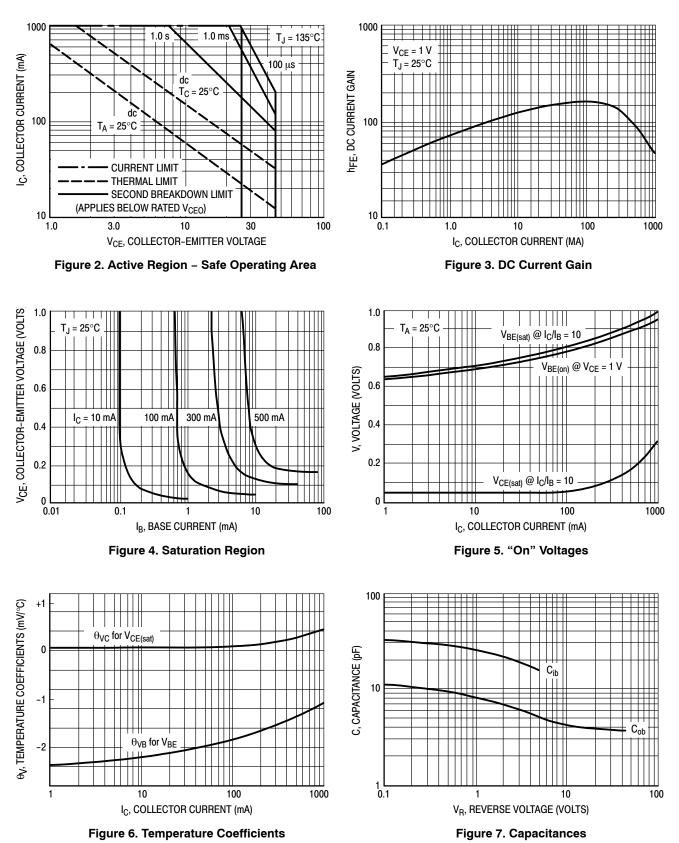
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•	•	•	•
Collector – Emitter Breakdown Voltage $(I_{C} = 10 \text{ mA}, I_{B} = 0)$	V <sub>(BR)CEO</sub>	45	-	_	Vdc
Collector – Emitter Breakdown Voltage $(I_C = 100 \ \mu\text{A}, I_E = 0)$	V <sub>(BR)CES</sub>	50	-	_	Vdc
Emitter – Base Breakdown Voltage $(I_E = 10 \ \mu A, I_C = 0)$	V <sub>(BR)EBO</sub>	5.0	-	_	Vdc
Collector Cutoff Current $(V_{CB} = 30 \text{ V}, I_E = 0)$	I <sub>CBO</sub>	-	-	100	nAdc
Collector Cutoff Current ( $V_{CE} = 45 \text{ V}, V_{BE} = 0$ )	I <sub>CES</sub>	_	-	100	nAdc
Emitter Cutoff Current ( $V_{EB} = 4.0 \text{ V}, I_C = 0$ )	I <sub>EBO</sub>	-	-	100	nAdc
ON CHARACTERISTICS			•	•	•
DC Current Gain $(I_C = 100 \text{ mA}, V_{CE} = 1.0 \text{ V})$ BC337-25 BC337-40 (I_C = 200 mA) (I_C = 1.0)(I_C)	h <sub>FE</sub>	100 160 250	- - -	630 400 630	-
(I <sub>C</sub> = 300 mA, V <sub>CE</sub> = 1.0 V)		60	-	-	
Base–Emitter On Voltage (I <sub>C</sub> = 300 mA, V <sub>CE</sub> = 1.0 V)	V <sub>BE(on)</sub>	-	-	1.2	Vdc
Collector – Emitter Saturation Voltage ( $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ )	V <sub>CE(sat)</sub>	_	-	0.7	Vdc
SMALL-SIGNAL CHARACTERISTICS		•		•	
Output Capacitance $(V_{CB} = 10 \text{ V}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>ob</sub>	-	15	-	pF
Current – Gain – Bandwidth Product	f <sub>T</sub>	-	210	-	MHz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.





### BC337, BC337-25, BC337-40



## BC337, BC337-25, BC337-40

### **ORDERING INFORMATION**

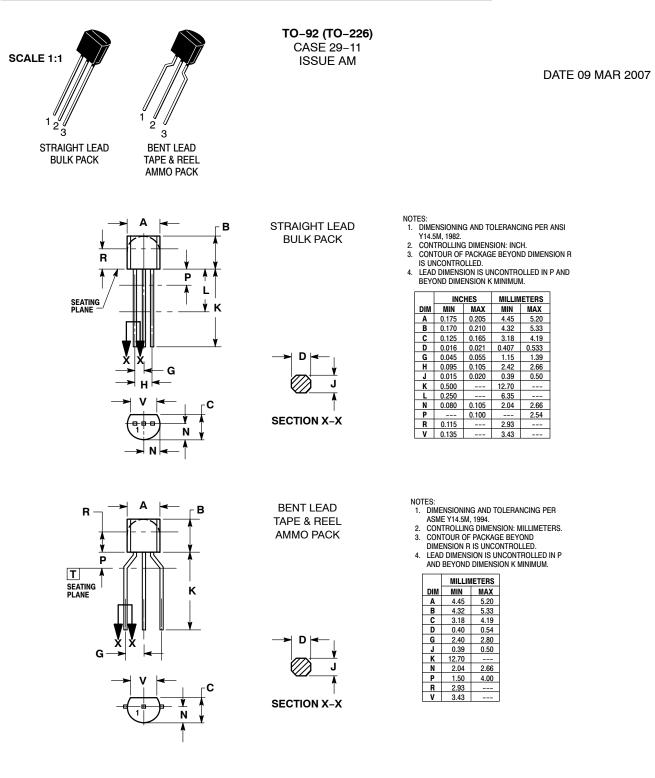
Device	Marking	Package	Shipping <sup>†</sup>
BC337G	7		5000 Units / Bulk
BC337RL1G	7		2000 / Tape & Reel
BC337-025G	7–25	TO-92 (Pb-Free)	5000 Units / Bulk
BC337-25RL1G	7–25		2000 / Tape & Reel
BC337-25RLRAG	7–25		2000 / Tape & Reel
BC337-25ZL1G	7–25		2000 / Ammo Box
BC337-040G	7–40		5000 Units / Bulk
BC337-40RL1G	7–40		2000 / Tape & Reel
BC337-40ZL1G	7–40		2000 / Ammo Box

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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### **STYLES ON PAGE 2**

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#### TO-92 (TO-226) CASE 29-11 ISSUE AM

### DATE 09 MAR 2007

STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR STYLE 6: PIN 1. GATE 2. SOURCE & SUBSTRATE 3. DRAIN STYLE 11: PIN 1. ANODE 2. CATHODE & ANODE 3. CATHODE STYLE 16: PIN 1. ANODE 2. GATE 3. CATHODE STYLE 21: PIN 1. COLLECTOR 2. EMITTER 3. BASE STYLE 22: PIN 1. VCC 2. GROUND 2 3. OUTPUT STYLE 31: PIN 1. GATE 2. DRAIN 3. SOURCE

	BASE EMITTER COLLECTOR
2.	SOURCE DRAIN GATE
2.	MAIN TERMINAL 1 Gate Main Terminal 2
2.	COLLECTOR BASE EMITTER
2.	SOURCE GATE DRAIN

2	1.	ANODE ANODE CATHODE
2	1. 2.	DRAIN Gate Source & Substrate
2	1. 2.	ANODE 1 GATE CATHODE 2
2	1. 2.	ANODE CATHODE NOT CONNECTED
2	1. 2.	GATE SOURCE DRAIN
2	1. 2.	CATHODE ANODE GATE

STYLE 33: PIN 1. RETURN 2. INPUT 3. OUTPUT

2.	CATHODE CATHODE ANODE
2.	BASE 1 EMITTER BASE 2
2.	EMITTER COLLECTOR BASE
	GATE ANODE CATHODE
2.	EMITTER Collector/Anode Cathode
2.	NOT CONNECTED ANODE CATHODE
2.	INPUT GROUND LOGIC

STYLE 4:

STYLE 5: PIN 1. DRAIN 2. SOURCE 3. GATE STYLE 10: PIN 1. CATHODE 2. GATE 3. ANODE STYLE 15: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 STYLE 20: PIN 1. NOT CONNECTED 2. CATHODE 3. ANODE STYLE 25: PIN 1. MT 1 2. GATE 3. MT 2 STYLE 30: PIN 1. DRAIN 2. GATE 3. SOURCE STYLE 35: PIN 1. DRAIN 2. GATE 3. SOURCE STYLE 35: PIN 1. GATE 2. COLLECTOR 3. EMITTER

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